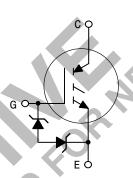
# Designer's™ Data Sheet

# **Insulated Gate Bipolar Transistor**

## N-Channel Enhancement-Mode Silicon Gate

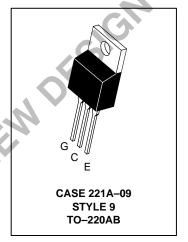
This Insulated Gate Bipolar Transistor (IGBT) uses an advanced termination scheme to provide an enhanced and reliable high voltage–blocking capability. Its new 600 V IGBT technology is specifically suited for applications requiring both a high temperature short circuit capability and a low  $V_{\text{CE(on)}}$ . It also provides fast switching characteristics and results in efficient operation at high frequencies. This new E–series introduces an energy efficient, ESD protected, and short circuit rugged device.

- Industry Standard TO-220 Package
- High Speed: E<sub>off</sub> = 65 μJ/A typical at 125°C
- High Voltage Short Circuit Capability 10 μs minimum at 125°C, 400 V
- Low On–Voltage 2.1 V typical at 20 A, 125°C
- Robust High Voltage Termination
- ESD Protection Gate-Emitter Zener Diodes



## **MGP21N60E**

IGBT IN TO-220
21 A @ 90°C
31 A @ 25°C
600 VOLTS
SHORT CIRCUIT RATED
LOW ON-VOLTAGE



#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V <sub>CES</sub>	600	Vdc
Collector–Gate Voltage ( $R_{GE} = 1.0 \text{ M}\Omega$ )	V <sub>CGR</sub>	600	Vdc
Gate-Emitter Voltage — Continuous	V <sub>GE</sub>	±20	Vdc
Collector Current — Continuous @ T <sub>C</sub> = 25°C — Continuous @ T <sub>C</sub> = 90°C — Repetitive Pulsed Current (1)	I <sub>C25</sub> I <sub>C90</sub> I <sub>CM</sub>	31 21 42	Adc Apk
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	142 1.14	Watts W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C
Short Circuit Withstand Time $(V_{CC} = 400 \text{ Vdc}, V_{GE} = 15 \text{ Vdc}, T_J = 125^{\circ}\text{C}, R_G = 20 \Omega)$	t <sub>sc</sub>	10	μs
Thermal Resistance — Junction to Case – IGBT  — Junction to Ambient	R <sub>θJC</sub> R <sub>θJA</sub>	0.9 65	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	T <sub>L</sub>	260	°C
Mounting Torque, 6–32 or M3 screw	10 lbf•in (1.13 N•m)		

<sup>(1)</sup> Pulse width is limited by maximum junction temperature. Repetitive rating.

**Designer's Data for "Worst Case" Conditions** — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

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### MGP21N60E

# **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ unless otherwise noted)

CI	naracteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector–to–Emitter Breakdown ( $V_{GE}$ = 0 Vdc, $I_{C}$ = 25 $\mu$ Adc) Temperature Coefficient (Positi		V <sub>(BR)CES</sub>	600 —	— 870	_	Vdc mV/°C
Emitter–to–Collector Breakdown Voltage (V <sub>GE</sub> = 0 Vdc, I <sub>EC</sub> = 100 mAdc)		V <sub>(BR)ECS</sub>	15	_	_	Vdc
Zero Gate Voltage Collector Curr ( $V_{CE} = 600 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}$ ) ( $V_{CE} = 600 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}$ ,		ICES	_		10 200	μAdc
Gate-Body Leakage Current (V <sub>G</sub>	<sub>E</sub> = ± 20 Vdc, V <sub>CE</sub> = 0 Vdc)	I <sub>GES</sub>	_	_	50	μAdc
ON CHARACTERISTICS (1)						
Collector-to-Emitter On-State Volume ( $V_{GE}$ = 15 Vdc, $I_{C}$ = 10 Adc) ( $V_{GE}$ = 15 Vdc, $I_{C}$ = 10 Adc, $T_{J}$ ( $V_{GE}$ = 15 Vdc, $I_{C}$ = 20 Adc)	·	V <sub>CE(on)</sub>	_ _ _	1.7 1.5 2.2	2.1	Vdc
Gate Threshold Voltage (V <sub>CE</sub> = V <sub>GE</sub> , I <sub>C</sub> = 1.0 mAdc) Threshold Temperature Coeffic	ient (Negative)	V <sub>GE(th)</sub>	4.0	6.0 10	8.0 —	Vdc mV/°C
Forward Transconductance (V <sub>CE</sub>	= 10 Vdc, I <sub>C</sub> = 20 Adc)	9 <sub>fe</sub>		8.6	_	Mhos
DYNAMIC CHARACTERISTICS						
Input Capacitance		C <sub>ies</sub>	7	1605	_	pF
Output Capacitance	$(V_{CE} = 25 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C <sub>oes</sub>		146	_	
Transfer Capacitance		C <sub>res</sub>	_	23	_	
SWITCHING CHARACTERISTICS	5 (1)					
Turn-On Delay Time		t <sub>d(on)</sub>	_	29	_	ns
Rise Time	$(V_{CC} = 360 \text{ Vdc}, I_{C} = 20 \text{ Adc},$	t <sub>r</sub>	_	60	_	
Turn-Off Delay Time	$V_{GE} = 15 \text{ Vdc}, L = 300 \mu\text{H}, \\ R_{G} = 20 \Omega)$	t <sub>d(off)</sub>	_	238	_	
Fall Time	Energy losses include "tail"	t <sub>f</sub>	_	140	_	
Turn-Off Switching Loss		E <sub>off</sub>	_	0.80	1.15	mJ
Turn-On Delay Time		t <sub>d(on)</sub>	_	28	_	ns
Rise Time	(V <sub>CC</sub> = 360 Vdc, I <sub>C</sub> = 20 Adc,	t <sub>r</sub>	_	62	_	
Turn-Off Delay Time	$V_{GE} = 15 \text{ Vdc}, L = 300 \mu\text{H}, \\ R_{G} = 20 \Omega, T_{J} = 125^{\circ}\text{C})$	t <sub>d(off)</sub>	_	338	_	
Fall Time	Energy losses include "tail"	t <sub>f</sub>	_	220	_	
Turn-Off Switching Loss		E <sub>off</sub>	_	1.3	_	mJ
Gate Charge		Q <sub>T</sub>	_	86	_	nC
	$(V_{CC} = 360 \text{ Vdc}, I_C = 20 \text{ Adc}, V_{GF} = 15 \text{ Vdc})$	Q <sub>1</sub>	_	18	_	1
	vGE = 13 vuc)	Q <sub>2</sub>	_	39	_	
NTERNAL PACKAGE INDUCTAN	ICE					
Internal Emitter Inductance	d 0.25" from package to emitter bond pad)	L <sub>E</sub>	_	7.5	_	nH

<sup>(</sup>Measured from the emitter lead 0.25° from package (1) Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

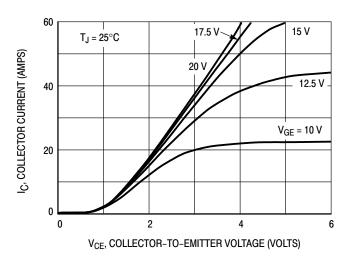


Figure 1. Output Characteristics

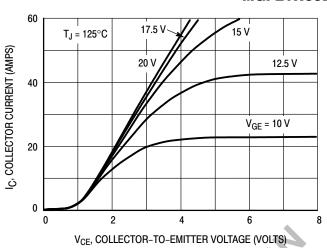
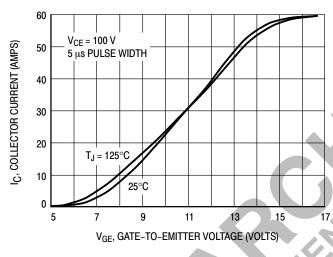


Figure 2. Output Characteristics



**Figure 3. Transfer Characteristics** 

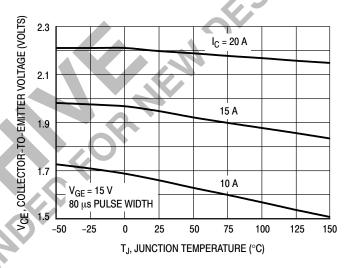


Figure 4. Collector–To–Emitter Saturation Voltage versus Junction Temperature

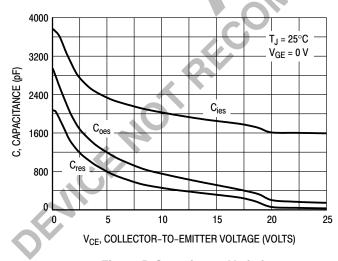


Figure 5. Capacitance Variation

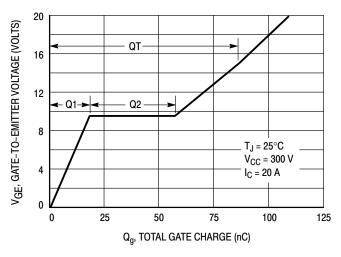


Figure 6. Gate-To-Emitter Voltage versus Total Charge

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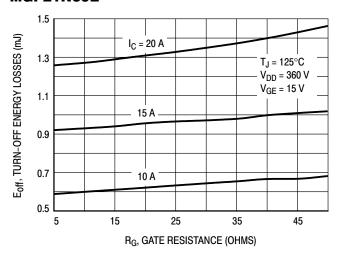


Figure 7. Turn-Off Losses versus **Gate Resistance** 

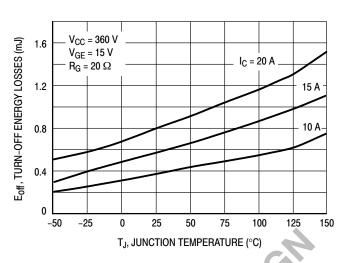
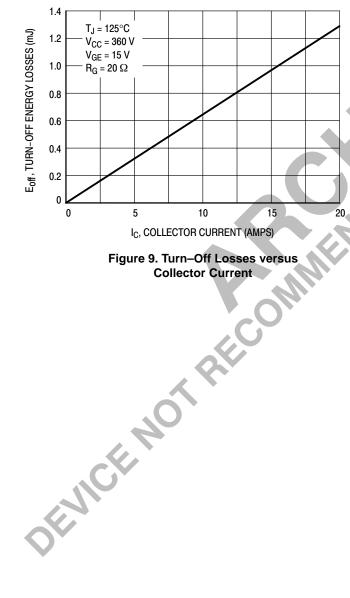


Figure 8. Turn-Off Losses versus **Junction Temperature** 



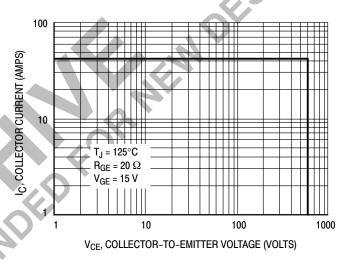
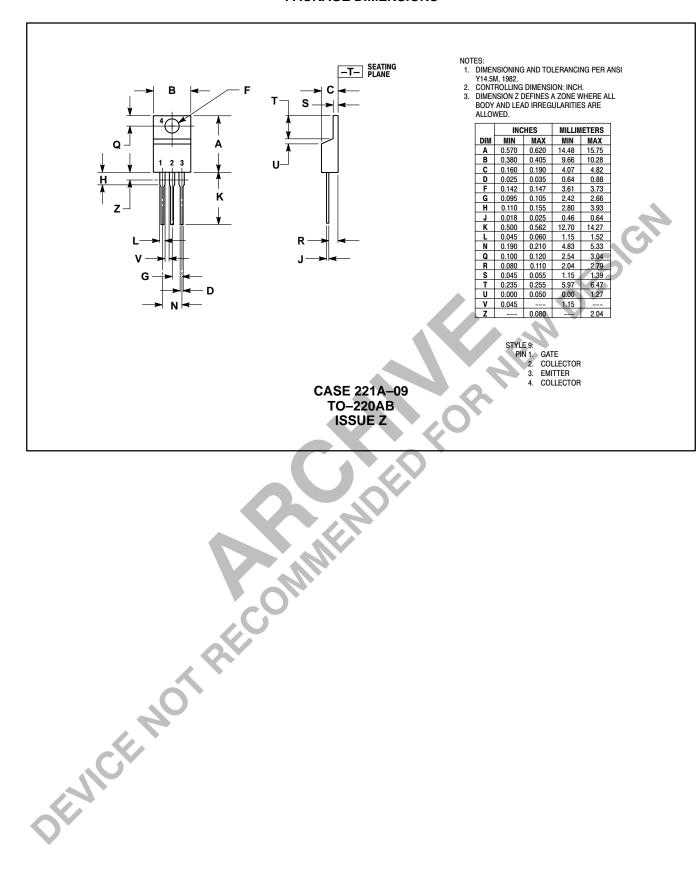


Figure 10. Reverse Biased Safe **Operating Area** 

### PACKAGE DIMENSIONS





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